## Notification about the transfer of the semiconductor business

The semiconductor business of Panasonic Corporation was transferred on September 1, 2020 to Nuvoton Technology Corporation (hereinafter referred to as "Nuvoton"). Accordingly, Panasonic Semiconductor Solutions Co., Ltd. became under the umbrella of the Nuvoton Group, with the new name of Nuvoton Technology Corporation Japan (hereinafter referred to as "NTCJ").

In accordance with this transfer, semiconductor products will be handled as NTCJ-made products after September 1, 2020. However, such products will be continuously sold through Panasonic Corporation.

Publisher of this Document is NTCJ.

If you would find description "Panasonic" or "Panasonic semiconductor solutions", please replace it with NTCJ.

\* Except below description page

"Request for your special attention and precautions in using the technical information and semiconductors described in this book"

Nuvoton Technology Corporation Japan

## **Panasonic**

# MOS FET

## FJ4B01120L Single P-channel MOS FET

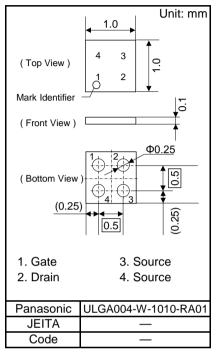
### Features

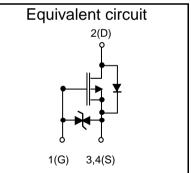
- Drain-source On-state Resistance : RDS(on) typ. = 40 m $\Omega$  ( VGS = -2.5 V )
- CSP( Chip Size Package )
- Halogen-free / RoHS compliant ( EU RoHS / UL-94 V-0 / MSL : Level 1 )
- Marking Symbol : 1F

### Packaging

Embossed type ( Thermo-compression sealing ) : 20 000 pcs / reel ( standard )

■ Absolute Maximum Ratings Ta = 25 °C							
Parameter		Symbol	Rating	Unit			
Drain-source Voltage		VDS	-12	V			
Gate-source Voltage	VGS	±8	V				
Drain Current		ID1 *1	-2.6	А			
	DC	ID2 *2	-4.2	Α			
		ID3 <sup>*3</sup>	-5.4	А			
	Pulsed *4	IDp1	-20	А			
		IDp2	-33	Α			
		IDp3	-43	Α			
Total Power Dissipation		PD1 *1	0.37	W			
		PD2 *2	0.94	W			
			1.5	W			
Channel Temperature		Tch	150	°C			
Operating Ambient Temperature		Topr	-40 to +85	°C			
Storage Temperature Range		Tstg	-55 to +150	°C			





Note \*1 FR4 board (25.4mm×25.4mm×t1.0mm), Min Cu 36mm<sup>2</sup> Copper.

\*2 FR4 board (25.4mm×25.4mm×t1.0mm), Full Cu.

\*3 Ceramic substrate (70mm×70mm×t1.0mm).

\*4 t = 10  $\mu s,$  Duty Cycle  $\leq$  1 %

## **Panasonic**

#### า าบนนบเ บเล่านลานจ

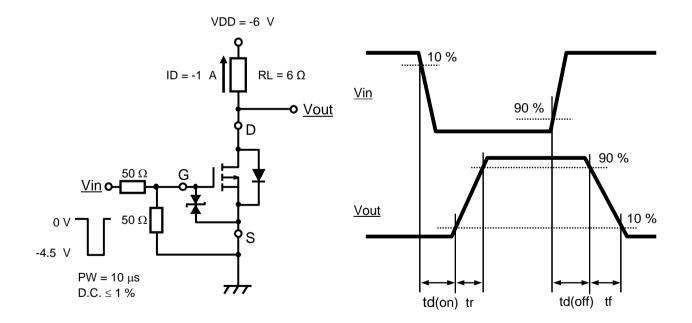
MOS FET FJ4B01120L

Electrical Characteristics Ta = 25	5 °C ± 3 °C					
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Drain-source Breakdown Voltage	VDSS	ID = -1 mA, VGS = 0	-12			V
Zero Gate Voltage Drain Current	IDSS	VDS = -12 V, VGS = 0			-1	μA
Gate-source Leakage Current	IGSS	$VGS = \pm 8 V$ , $VDS = 0 V$			±10	μA
Gate-source Threshold Voltage	Vth	ID = -2 mA, VDS = -10 V	-0.3		-1.0	V
Drain-source On-state Resistance	RDS(on)1	ID = -2 A, VGS = -4.5 V		34	51	mΩ
	RDS(on)2	ID = -2 A, VGS = -2.5 V		40	61	
	RDS(on)3	ID = -0.2 A, VGS = -1.8 V		48	85	
	RDS(on)4	ID = -0.1 A, VGS = -1.5 V		57	170	
Body Diode Forward Voltage	VF(s-d)	IF = -0.2 A, VGS = 0 V		-0.7	-1.2	V
Input Capacitance <sup>*1</sup>	Ciss	VDS = -10 V, VGS = 0 V f = 1 MHz		814		pF
Output Capacitance <sup>*1</sup>	Coss			201		
Reverse Transfer Capacitance <sup>*1</sup>	Crss	1 = 1 WI 12		187		
Turn-on Delay Time *1,*2	td(on)	VDD = -6 V, VGS = 0 to -4.5 V		6		20
Rise Time <sup>*1,*2</sup>	tr	ID = -1 A		4		
Turn-off Delay Time *1,*2	td(off)	VDD = -6 V, VGS = -4.5 to 0 V		63		ns
Fall Time <sup>*1,*2</sup>	tf	ID = -1 A		46		
Total Gate Charge <sup>*1</sup>	Qg			10.7		nC
Gate-source Charge <sup>*1</sup>	Qgs	VDD = -6 V, VGS = -4.5 V ID = -1 A		1.4		
Gate-drain Charge <sup>*1</sup>	Qgd			2.1		

Note Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

\*1 Guaranteed by design, not subject to production testing.

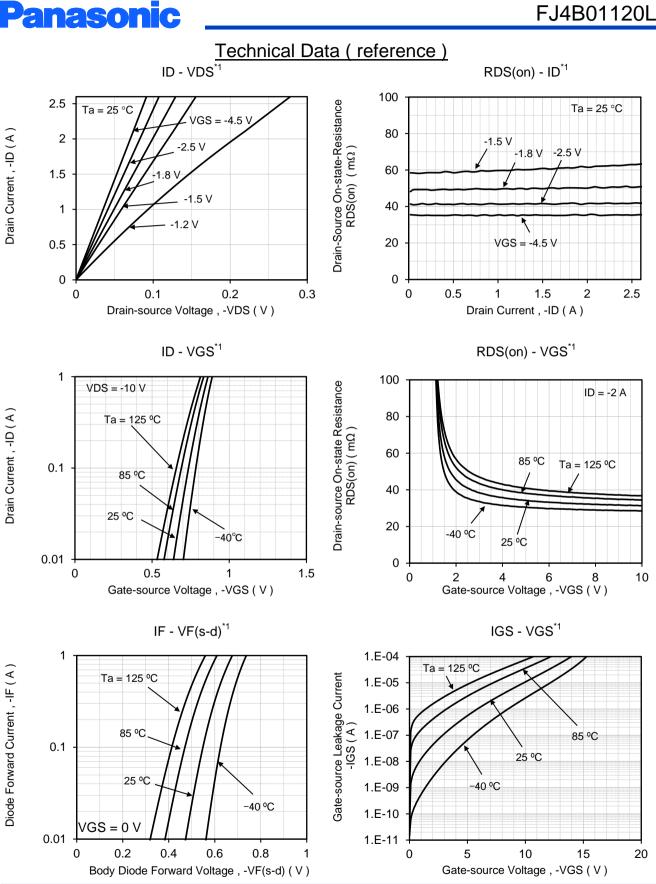
\*2 Measurement circuit for Turn-on Delay Time / Rise Time / Turn-off Delay Time / Fall Time.



### Electrical State Discharge Characteristics

Standard	Test Type	Symbol	Conditions	Class	Value	Unit
AEC-Q101	Human Body Model	HBM	$C = 100 \text{ pF}, R = 1.5 \text{ k}\Omega$	H1C	> 1k to ≤ 2k	V
	Machine Model	MM	$C = 200 \text{ pF}, R = 0 \Omega$	M2	> 100 to ≤ 200	V

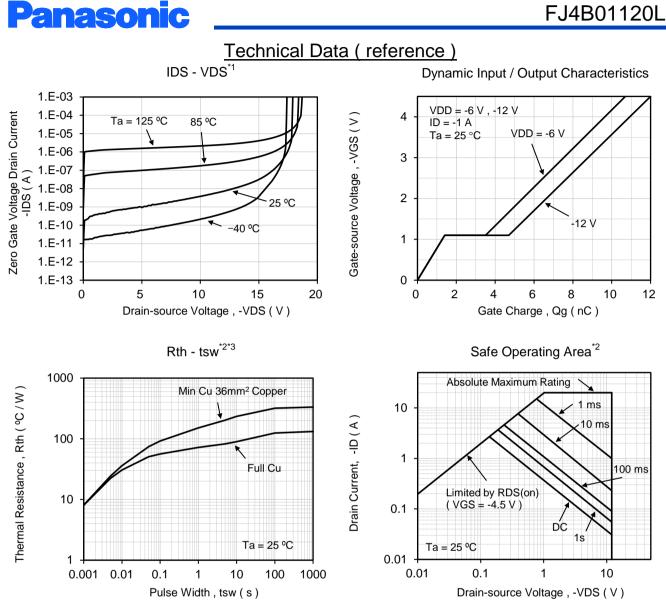
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Established : 2015/01/19 Revised : 2018/02/08

### MOS FET FJ4B01120L



#### Note

- \*1 Pulse measurement
- \*2 FR4 board (25.4mm×25.4mm×t1.0mm), Min Cu 36mm<sup>2</sup> Copper.
- \*3 FR4 board (25.4mm×25.4mm×t1.0mm), Full Cu.

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Outline

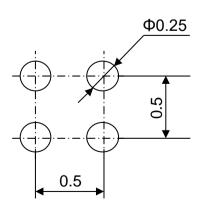
MOS FET FJ4B01120L

Unit: mm

1.0±0.03 4 3  $1.0 \pm 0.03$ (Top View) 2 1  $\bigcirc$ Mark Identifier -**0.1**±0.02 (Front View)  $\Phi0.25{\scriptstyle\pm0.03}$ 0.5 (Bottom View) 3 (0.25) (0.25) 0.5

■ Land & Stencil Pattern (Reference)

Unit: mm



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